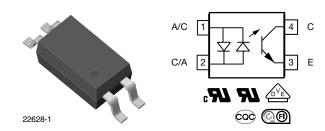


Vishay Semiconductors

Optocoupler, Phototransistor Output, AC Input, SSOP-4, Half Pitch, Mini-Flat Package



DESCRIPTION

The VOS627A series has a GaAs infrared emitting diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a 4-pin 50 mil lead pitch mini-flat package.

It features a high current transfer ratio at low input current, low coupling capacitance, and high isolation voltage.

The coupling devices are designed for signal transmission between two electrically separated circuits.

FEATURES

- High CTR with low input current
- Low profile package (half pitch)
- High collector emitter voltage V_{CEO} = 80 V
- Isolation test voltage = 3750 V_{RMS}
- · Low coupling capacitance
- · High common mode transient immunity
- Material categorization:
 For definitions of compliance please see www.vishay.com/doc?99912





COMPLIANT
HALOGEN
FREE
GREEN

APPLICATIONS

- Telecom
- · Industrial controls
- · Battery powered equipment
- Office machines
- Programmable controllers

AGENCY APPROVALS

Safety application model number covering all products in this datasheet is VOS627A. This model number should be used when consulting safety agency documents.

- UL1577, file no. E52744
- cUL
- DIN EN 60747-5-5 (VDE 0884-5), available with option 1
- FIMKO EN 60065, EN 60950-1
- CQC GB4943.1-2011 and GB8898-2011 (suitable for installation altitude below 2000 m)

ORDERING INFORMATION						
V O S 6 2 7 PART NUMBER	A - # CTR	X 0 0 [TAPE AND REEL	SSOP-4 ≥ 5 mm		
AGENCY CERTIFIED/PACKAGE	CTR (%)					
AGENOT GENTINED/T AGRAGE	± 5 mA					
UL, cUL, FIMKO, CQC	50 to 600	63 to 125	100 to 200	160 to 320		
SSOP-4, 50 mil pitch	VOS627AT	VOS627A-2T	VOS627A-3T	VOS627A-4T		
UL, cUL, FIMKO, CQC, VDE (option 1)	50 to 600	63 to 125	100 to 200	160 to 320		
SSOP-4, 50 mil pitch	VOS627A-X001T	VOS627A-2X001T	VOS627A-3X001T	VOS627A-4X001T		

Note

Additional options may be possible, please contact sales office.



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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
INPUT	•					
Reverse voltage		V_{R}	6	V		
Power dissipation		P _{diss}	70	mW		
Surge forward current	t _p ≤ 10 μs	I _{FSM}	1.5	А		
Forward current		I _F	50	mA		
OUTPUT	•		<u>. </u>			
Collector emitter voltage		V _{CEO}	80	V		
Emitter collector voltage		V _{ECO}	7	V		
Collector current		I _C	50	mA		
Power dissipation		P _{diss}	150	mW		
COUPLER	•		<u>. </u>			
Isolation test voltage between emitter and detector	t = 1 min	V _{ISO}	3750	V_{RMS}		
Total power dissipation		P _{tot}	170	mW		
Storage temperature range		T _{stg}	-55 to +150	°C		
Ambient temperature range		T _{amb}	-55 to +110	°C		
Junction temperature		Tj	125	°C		
Soldering temperature (1)	t = 10 s	T _{sld}	260	°C		

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
 implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
 maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Refer to reflow profile for soldering conditions for surface mounted devices.

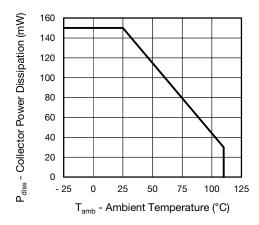


Fig. 1 - Power Dissipation vs. Ambient Temperature

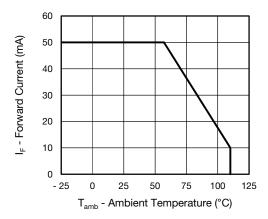


Fig. 2 - Forward Current vs. Ambient Temperature



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ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
INPUT							
Forward voltage	I _F = 50 mA	V_{F}		1.1	1.5	V	
Reverse current	V _R = 6 V	I_R		0.01	10	μA	
Capacitance	$V_R = 0 V, f = 1 MHz$	CI		7.3		pF	
OUTPUT							
Collector emitter leakage current	V _{CE} = 10 V	I _{CEO}		0.3	100	nA	
Collector emitter breakdown voltage	I _C = 100 μA	BV _{CEO}	80			V	
Emitter collector breakdown voltage	I _E = 10 μA	BV_{ECO}	7			V	
Collector emitter capacitance	V _{CE} = 5 V, f = 1 MHz	C_{CE}		5		pF	
COUPLER							
Collector emitter saturation voltage	$I_F = 5 \text{ mA}, I_C = 1.25 \text{ mA}$	V _{CEsat}		0.25	0.4	V	
Cut-off frequency	$I_F = 10 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 100 \Omega$	f _{ctr}		155		kHz	

Note

• Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
I _C /I _F	$I_F = \pm 5$ mA, $V_{CE} = 5$ V	VOS627A	CTR	50		600	%
		VOS627A-2	CTR	63		125	%
		VOS627A-3	CTR	100		200	%
		VOS627A-4	CTR	160		320	%

SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
NON-SATURATED	NON-SATURATED						
Rise and fall time		t _r		3		μs	
Fall time	$I_C = 2 \text{ mA}, V_{CC} = 5 \text{ V},$	t _f		3		μs	
Turn-on time	$R_L = 100 \Omega$	t _{on}		6		μs	
Turn-off time		t _{off}		4		μs	
SATURATED							
Rise and fall time	$I_F = 1.6$ mA, $V_{CC} = 5$ V, $R_L = 1.9$ k Ω	t _r		3		μs	
Fall time		t _f		12		μs	
Turn-on time		t _{on}		4		μs	
Turn-off time		t _{off}		18		μs	

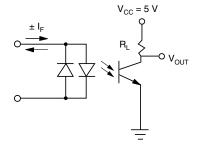


Fig. 3 - Test Circuit

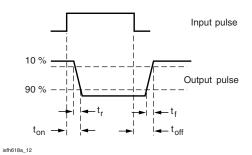


Fig. 4 - Test Circuit and Waveforms



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SAFETY AND INSULATION RATINGS						
PARAMETER		SYMBOL	VALUE	UNIT		
MAXIMUM SAFETY RATINGS						
Output safety power		P _{SO}	300	mW		
Input safety current		I _{si}	200	mA		
Safety temperature		T _S	150	°C		
Comparative tracking index		CTI	175			
INSULATION RATED PARAMETERS						
Maximum withstanding isolation voltage	40 % to 60 % RH, AC test of 1 min	V _{ISO}	3750	V _{RMS}		
Maximum transient isolation voltage		V _{IOTM}	6000	V _{peak}		
Maximum repetitive peak isolation voltage		V _{IORM}	565	V _{peak}		
Insulation resistance	$T_{amb} = 25 ^{\circ}\text{C}, V_{DC} = 500 \text{V}$	R _{IO}	≥ 10 ¹²	Ω		
Isolation resistance	T _{amb} = 100 °C, V _{DC} = 500 V	R _{IO}	≥ 10 ¹¹	Ω		
Climatic classification (according to IEC 68 part 1)			55/110/21			
Environment (pollution degree in accordance to DIN VDE 0109)			2			
Creepage distance			≥ 5	mm		
Clearance distance			≥ 5	mm		
Insulation thickness		DTI	≥ 0.4	mm		

Note

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

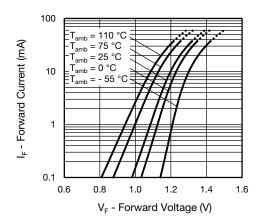


Fig. 5 - Forward Voltage vs. Forward Current

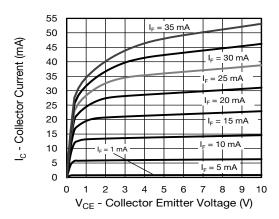
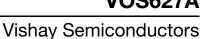


Fig. 6 - Collector Current vs. Collector Emitter Voltage

[•] As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.





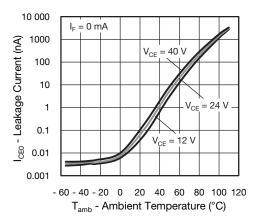


Fig. 7 - Leakage Current vs. Ambient Temperature

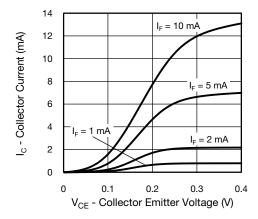


Fig. 8 - Collector Current vs. Collector Emitter Voltage

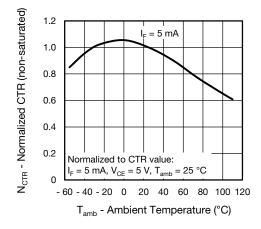


Fig. 9 - Normalized Current Transfer Ratio vs.
Ambient Temperature

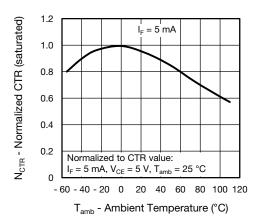


Fig. 10 - Normalized Current Transfer Ratio vs.
Ambient Temperature

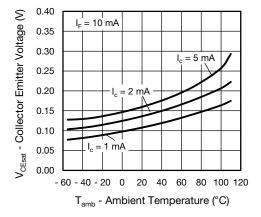


Fig. 11 - Collector Emitter Voltage vs. Ambient Temperature

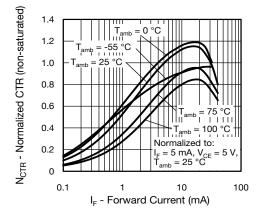


Fig. 12 - Normalized CTR vs. Forward Current



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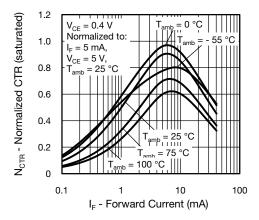


Fig. 13 - Normalized CTR vs. Forward Current

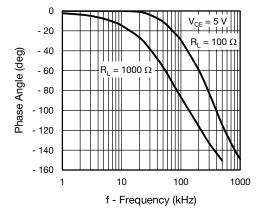


Fig. 14 - Frequency vs. Phase Angle

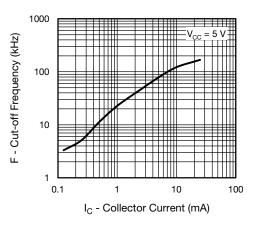


Fig. 15 - Frequency vs. Collector Current

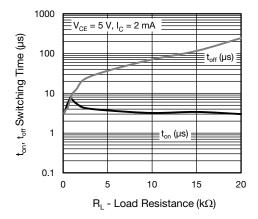
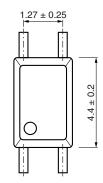


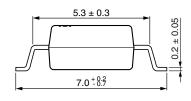
Fig. 16 - Switching Time vs. Load Resistance

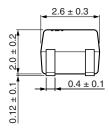


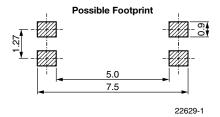


PACKAGE DIMENSIONS in millimeters

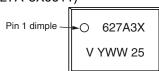








PACKAGE MARKING (example of VOS627A-3X001T)



Notes

- Option 1 is reflected with letter "X".
- Tape and reel suffix (T) is not part of the package marking.
- VOS627AT can be marked as 627A1, 627A2, 627A3, or 627A4.
- VOS627A-X001T can be marked as 627A1X, 627A2X, 627A3X, or 627A4X.

TAPE AND REEL DIMENSIONS in millimeters

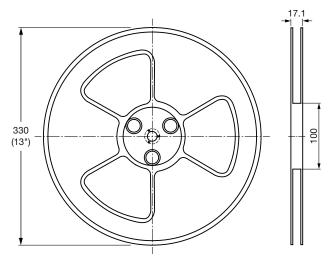


Fig. 17 - Reel Dimensions (3000 units per reel)



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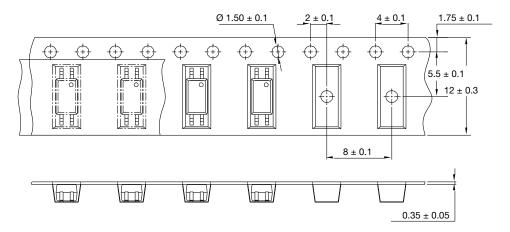


Fig. 18 - Tape Dimensions



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